

60 V, 6 A PNP high power bipolar transistor 9 December 2014

Product data sheet

1. General description

PNP high power bipolar transistor in a SOT669 (LFPAK56) Surface-Mounted Device (SMD) power plastic package.

NPN complement: PHPT60606NY.

2. Features and benefits

- High thermal power dissipation capability
- Suitable for high temperature applications up to 175 °C
- Reduced Printed-Circuit Board (PCB) requirements comparing to transistors in DPAK
 - High energy efficiency due to less heat generation
 - AEC-Q101 qualified

3. Applications

- Power management
- Load switch
- Linear mode voltage regulator
- Backlighting applications
- Motor drive
- Relay replacement

4. Quick reference data

Table 1. Quick reference data							
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	-60	V
I _C	collector current			-	-	-6	А
I _{CM}	peak collector current	$t_p \le 1 ms; pulsed$		-	-	-12	А
R _{CEsat}	collector-emitter saturation resistance	I_{C} = -6 A; I_{B} = -600 mA; pulsed; $t_{p} \le 300$ μs; δ ≤ 0.02; T_{amb} = 25 °C		-	66	88	mΩ



60 V, 6 A PNP high power bipolar transistor

5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter	mb	C
2	Е	emitter		в
3	Е	emitter	q	1×
4	В	base	មុច្ចមុ	sym132
mb	С	collector	1 2 3 4 LFPAK56; Power- SO8 (SOT669)	

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PHPT60606PY	LFPAK56; Power-SO8	Plastic single-ended surface-mounted package (LFPAK56; Power-SO8); 4 leads	SOT669			

7. Marking

Table 4. Marking codes	
Type number	Marking code
PHPT60606PY	0606PAB

60 V, 6 A PNP high power bipolar transistor

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

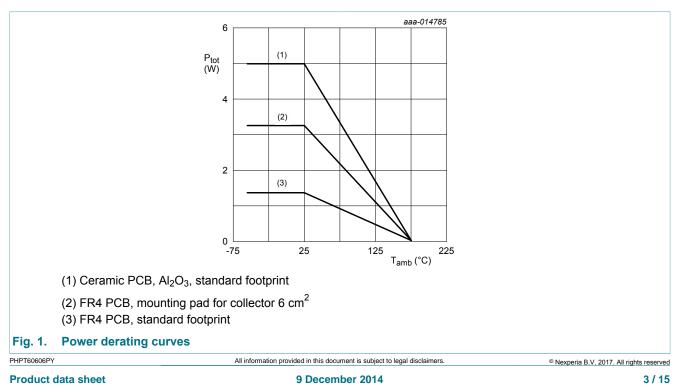
Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	-60	V
V _{CEO}	collector-emitter voltage	open base		-	-60	V
V _{EBO}	emitter-base voltage	open collector		-	-8	V
I _C	collector current			-	-6	А
I _{CM}	peak collector current	$t_p \le 1 ms$; pulsed		-	-12	А
I _B	base current			-	-800	mA
I _{BM}	peak base current	$t_p \le 1 ms$; pulsed		-	-1.2	А
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	1.35	W
			[2]	-	3.25	W
			[3]	-	5	W
			[4]	-	25	W
Tj	junction temperature			-	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated mounting pad for collector 6 cm².

[3] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.

[4] Power dissipation from junction to mounting base.

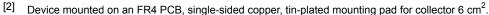


60 V, 6 A PNP high power bipolar transistor

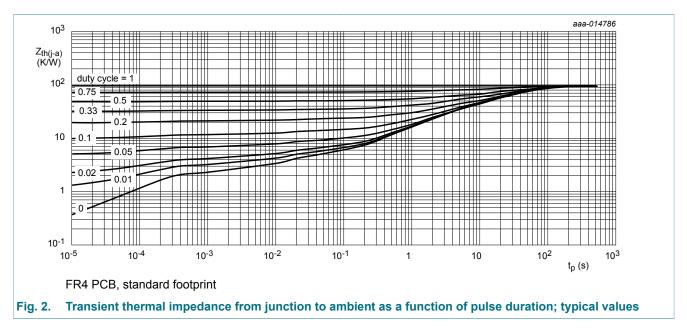
9. Thermal characteristics

Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
ui(j-a)	thermal resistance	in free air	[1]	-	-	111	K/W
	from junction to		[2]	-	-	46	K/W
	ambient		[3]	-	-	30	K/W
R _{th(j-mb)}	thermal resistance from junction to mounting base			-	-	6	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.





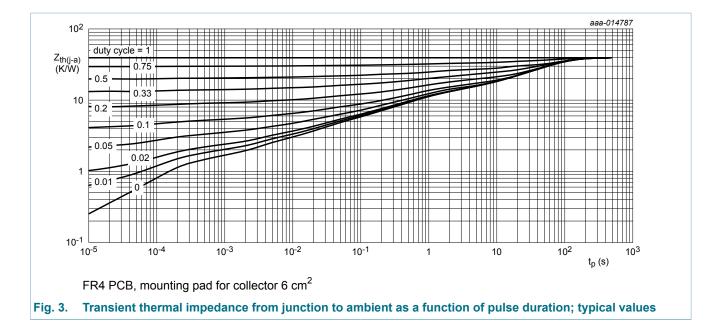


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60 V, 6 A PNP high power bipolar transistor



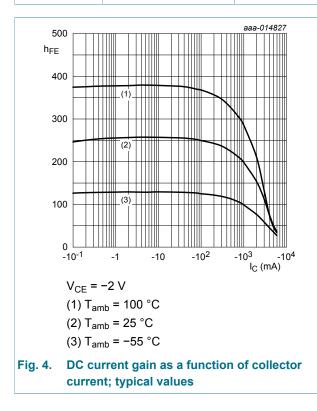
10. Characteristics

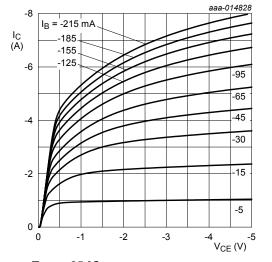
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	V _{CB} = -48 V; I _E = 0 A; T _{amb} = 25 °C	-	-	-100	nA
	current	V_{CB} = -48 V; I _E = 0 A; T _j = 150 °C	-	-	-50	μA
I _{CES}	collector-emitter cut-off current	V_{CE} = -48 V; V_{BE} = 0 V; T_{amb} = 25 °C	-	-	-100	nA
I _{EBO}	emitter-base cut-off current	V _{EB} = -8 V; I _C = 0 A; T _{amb} = 25 °C	-	-	-100	nA
h _{FE}	DC current gain	V_{CE} = -2 V; I _C = -500 mA; T _{amb} = 25 °C	120	200	-	
		V_{CE} = -2 V; I _C = -1 A; t _p ≤ 300 µs; $\delta \le 0.02$; T _{amb} = 25 °C; pulsed	110	180	-	
		V_{CE} = -2 V; I _C = -3 A; t _p ≤ 300 µs; δ ≤ 0.02; T _{amb} = 25 °C; pulsed	60	100	-	
		V_{CE} = -2 V; I _C = -6 A; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	20	30	-	
V _{CEsat}	collector-emitter saturation voltage	I_C = -1 A; I_B = -50 mA; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-75	-110	mV
	0	I_C = -3 A; I_B = -300 mA; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C; pulsed	-	-155	-230	mV
		I_{C} = -6 A; I_{B} = -600 mA; pulsed; $t_{p} \le 300$ μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-395	-525	mV
R _{CEsat}	collector-emitter saturation resistance	I_{C} = -6 A; I_{B} = -600 mA; pulsed; t_{p} ≤ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C	-	66	88	mΩ

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60 V, 6 A PNP high power bipolar transistor

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{BEsat}	base-emitter saturation voltage	I_{C} = -1 A; I_{B} = -50 mA; pulsed; $t_{p} \le 300 \ \mu$ s; δ ≤ 0.02 ; T_{amb} = 25 °C	-	-0.85	-0.95	V
		I _C = -3 A; I _B = -300 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	-1	-1.1	V
		I_{C} = -6 A; I_{B} = -600 mA; pulsed; $t_{p} \le 300 \ \mu$ s; δ ≤ 0.02; T_{amb} = 25 °C	-	-1.1	-1.3	V
V _{BEon}	base-emitter turn-on voltage	V_{CE} = -2 V; I _C = -0.5 A; T _{amb} = 25 °C	-	-0.75	-0.85	V
t _d	delay time	V_{CC} = -12.5 V; I _C = -3 A; I _{Bon} = -150 mA; I _{Boff} = 150 mA; T _{amb} = 25 °C	-	15	-	ns
t _r	rise time		-	110	-	ns
t _{on}	turn-on time		-	125	-	ns
ts	storage time		-	185	-	ns
t _f	fall time		-	70	-	ns
t _{off}	turn-off time		-	255	-	ns
f _T	transition frequency	V _{CE} = -10 V; I _C = -500 mA; f = 100 MHz; T _{amb} = 25 °C	-	110	-	MHz
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	57	-	pF









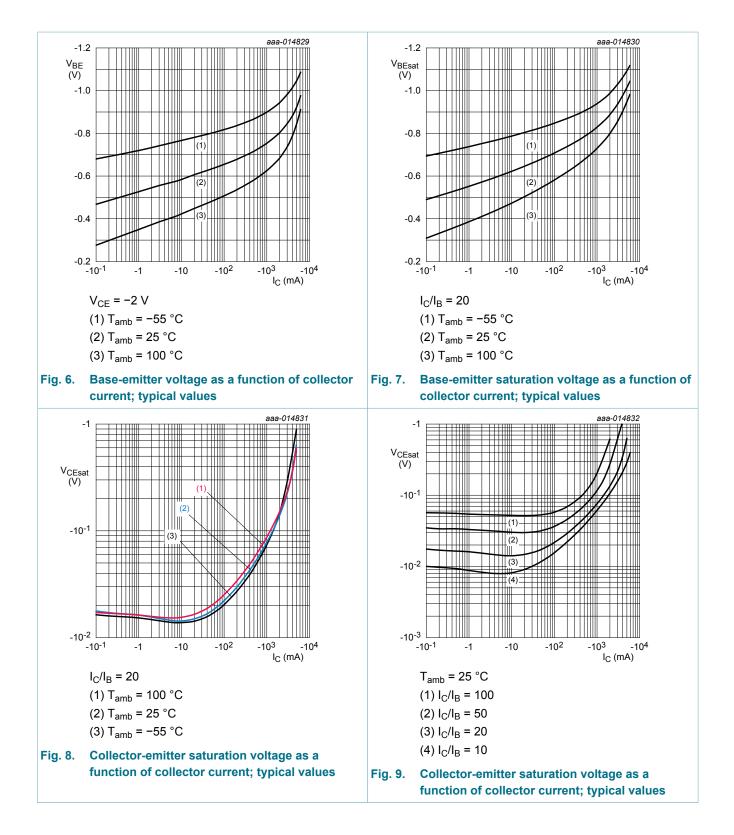
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6/15

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60 V, 6 A PNP high power bipolar transistor

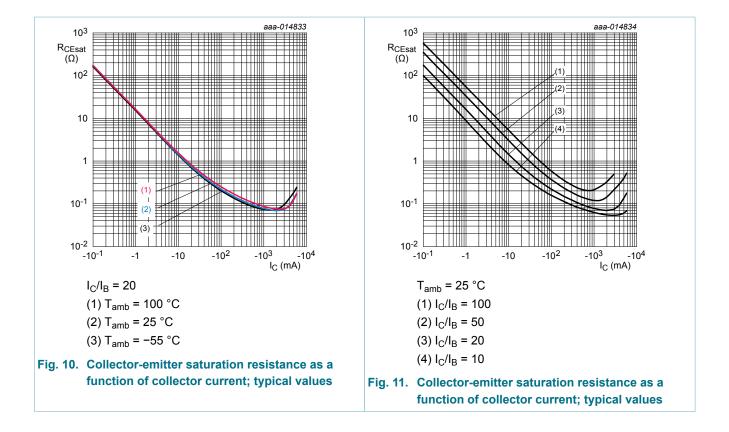


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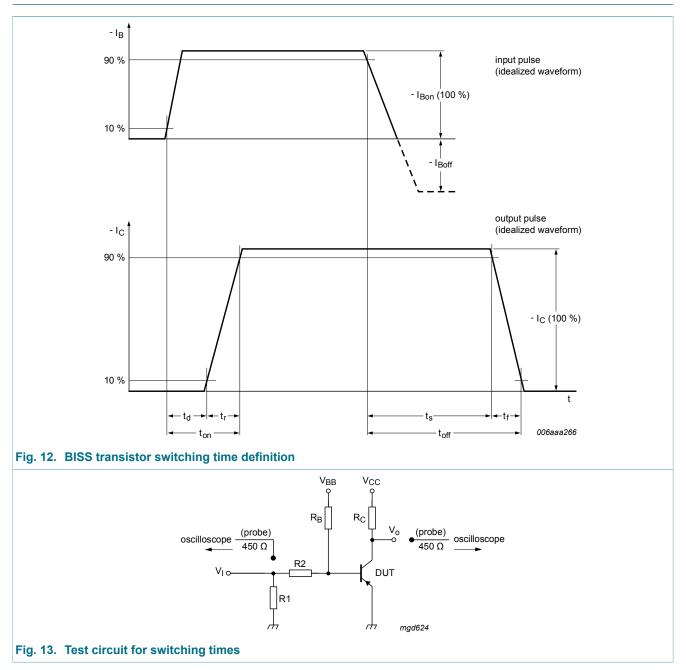
60 V, 6 A PNP high power bipolar transistor



PHPT60606PY

8/15

60 V, 6 A PNP high power bipolar transistor



11. Test information

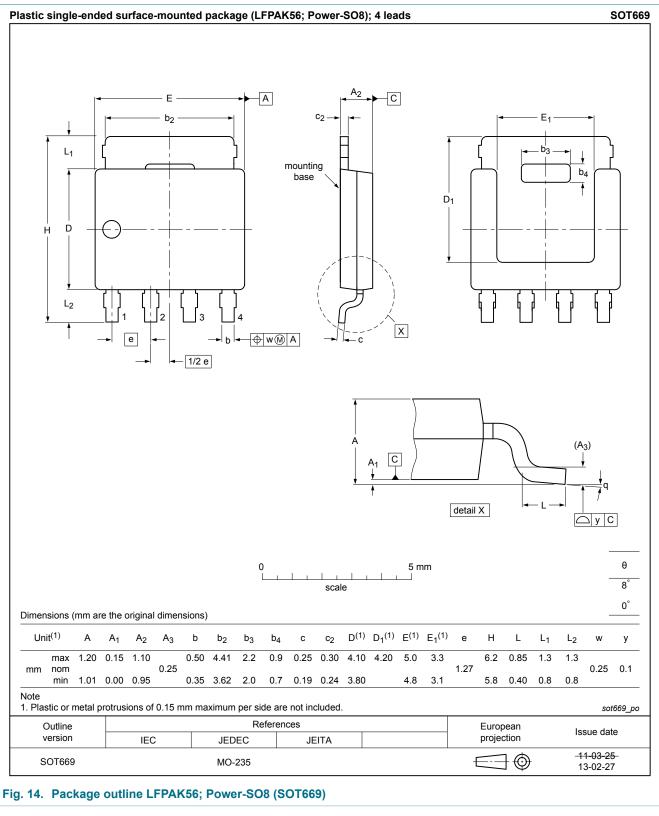


This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

PHPT60606PY

60 V, 6 A PNP high power bipolar transistor

12. Package outline



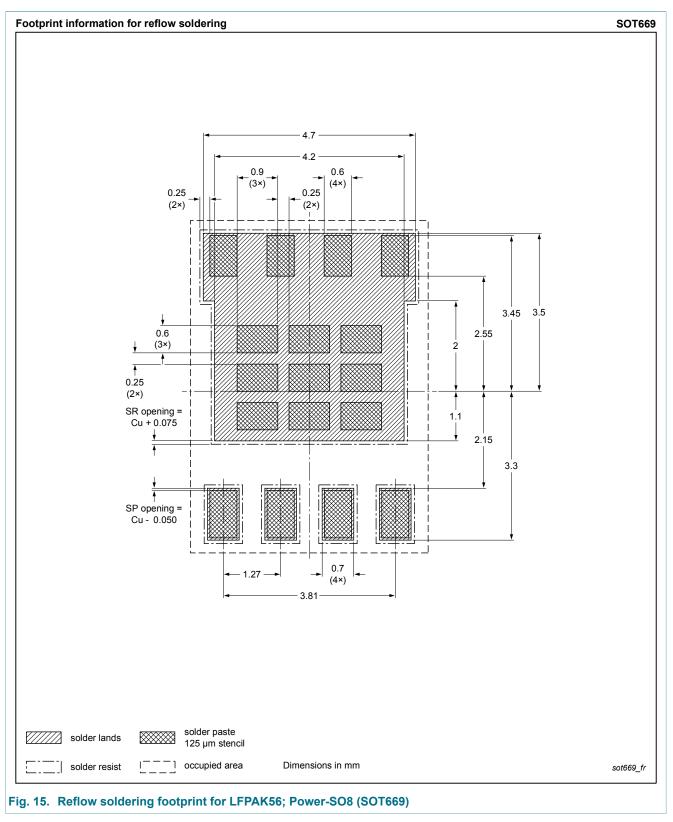
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13. Soldering



PHPT60606PY

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14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PHPT60606PY v.1	20141209	Product data sheet	-	-		

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15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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60 V, 6 A PNP high power bipolar transistor

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PHPT60606PY

60 V, 6 A PNP high power bipolar transistor

16. Contents

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Quick reference data	1
5	Pinning information	2
6	Ordering information	2
7	Marking	2
8	Limiting values	3
9	Thermal characteristics	4
10	Characteristics	5
11	Test information	9
11.1	Quality information	9
12	Package outline	10
13	Soldering	11
14	Revision history	12
15	Legal information	13
15.1	Data sheet status	13
15.2	Definitions	13
15.3	Disclaimers	13
15.4	Trademarks	14

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PHPT60606PY